



### HOA0862-T55



**HOA Series Infrared Transmissive Sensor, Transistor Output, Two Mounting Tabs, Plastic Package**

*Actual product appearance may vary.*

#### Features

- Phototransistor output
- Accurate position sensing
- Four mounting configurations
- 0.125 in [3.18 mm] slot width
- Choice of detector aperture
- Choice of opaque or IR transmissive housings

#### Description

The HOA086X/087X series consists of an infrared emitting diode facing an NPN silicon phototransistor encased in a black thermoplastic housing. The phototransistor switching takes place whenever an opaque object passes through the slot between emitter and detector. This series allows the user to choose from available options: (1) mounting tab configurations, (2) lead spacing, (3) electro-optical characteristics, (4) detector aperture size, and (5) housing materials.

The HOA86X series utilizes an IR transmissive polysulfone housing which features smooth optical faces without external aperture openings; this feature is desirable when aperture blockage from airborne contaminants is a possibility. The HOA087X series employs an opaque polysulfone housing with aperture openings for use in applications in which maximum rejection of ambient light is important and in situations where maximum position resolution is desired. The HOA086X/087X series employs plastic molded components. For additional component information see SEP8506 and SDP8406.

Housing material is polysulfone. Housings are soluble in chlorinated hydrocarbons and ketones. Recommended cleaning agents are methanol and isopropanol.

Product Specifications	
Series Name	Transmissive Sensor
Product Type	IR Switch
On-State Collector Current	1.80 mA
Output	Transistor
Mounting Configuration	Two Mounting Tabs
Package Components	Plastic
Package Color	Black
Forward Current	20 mA
Continuous Forward Current	50 mA
Forward Voltage	1.6 V
Reverse Breakdown Voltage	3 V
Reverse Current	10 $\mu$ A
Rise and Fall Time	15 $\mu$ s
Power Dissipation	100 mW
Operating Temperature Range	-40 °C to 85 °C [-40 °F to 185 °F]
Dark Current	100 nA
Collector DC Current	30 mA
Collector-Emitter Breakdown Voltage	30 V
Emitter-Collector Breakdown Voltage	5 V
Collector-Emitter Saturation Voltage	0.6 V
Availability	Global
Sensor Aperture	1,52 mm x 1,27 mm [0.060 in x 0.050 in]
Slot Width	3,18 mm [0.125 in]